TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (U-MOSⅢ)

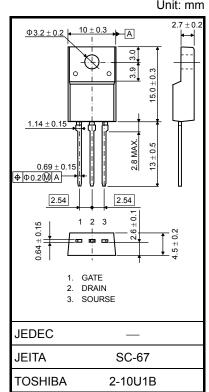
TJ70A06J3

Chopper Regulator, DC-DC Converter Applications Motor Drive Applications

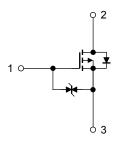
- 4.5-V gate drive
- Low drain-source ON resistance: R_{DS} (ON) = 5.6 m Ω (typ.)
- High forward transfer admittance: $|Y_{fs}| = 75 \text{ S} (\text{typ.})$
- Low leakage current: $I_{DSS} = -100 \ \mu A \ (max) \ (V_{DS} = -60 \ V)$
- Enhancement-model: $V_{th} = -0.8$ to -2.0 V ($V_{DS} = -10$ V, $I_D = -1$ mA)

Absolute Maximum Ratings (Ta = 25°C)

| Characteristics | | Symbol | Rating | Unit |
|--|----------------|------------------|------------|------|
| Drain-source voltage | | V _{DSS} | -60 | V |
| Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$) | | V _{DGR} | -60 | V |
| Gate-source voltage | | V _{GSS} | ±20 | V |
| Drain current | DC (Note 1) | I _D | -70 | А |
| | Pulse (Note 1) | I _{DP} | -280 | A |
| Drain power dissipation (Tc = 25° C) | | PD | 54 | W |
| Single pulse avalanche energy (Note 2) | | E _{AS} | 355 | mJ |
| Avalanche current | | I _{AR} | -70 | А |
| Repetitive avalanche energy (Note 3) | | E _{AR} | 5.4 | mJ |
| Channel temperature (Note 4) | | T _{ch} | 175 | °C |
| Storage temperature range (Note 4) | | T _{stg} | -55 to 175 | °C |



Weight: 1.7 g (typ.)



Thermal Characteristics

| Characteristics | Symbol | Max | Unit |
|--|------------------------|------|------|
| Thermal resistance, channel to case | R _{th (ch-c)} | 2.78 | °C/W |
| Thermal resistance, channel to ambient | R _{th (ch−a)} | 125 | °C/W |

- Note 1: Please use devises on condition that the channel temperature is below 175 °C.
- Note 2: $V_{DD} = -25 \text{ V}, \text{ T}_{ch} = 25^{\circ}\text{C}, \text{ L} = 98 \text{ }\mu\text{H}, \text{ R}_{G} = 25 \Omega, \text{ I}_{AR} = -70 \text{ A}$
- Note 3: Repetitive rating; pulse width limited by maximum channel temperature.
- Note 4: The definitions of the absolute maximum channel temperature and storage temperatures are based on AEC-Q101.
- Note 5: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic sensitive device. Please handle with caution.

Unit: mm

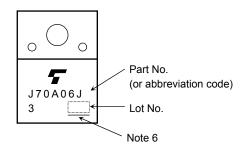
Electrical Characteristics (Ta = 25°C)

| Chara | octeristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--|----------------------|---|---|------|------|------|------|
| Gate leakage cur | rent | I _{GSS} | $V_{GS} = \pm 16$ V, $V_{DS} = 0$ V | _ | _ | ±10 | μΑ |
| Drain cut-OFF cu | rrent | I _{DSS} | $V_{DS} = -60 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$ | | _ | -10 | μA |
| Drain-source breakdown voltage | | V (BR) DSS | $I_D = -10 \text{ mA}, V_{GS} = 0 \text{ V}$ | -60 | | | V |
| | | V (BR) DSX | $I_D = -10 \text{ mA}, \text{ V}_{GS} = 20 \text{ V}$ | -35 | | | |
| Gate threshold vo | oltage | V _{th} | $V_{DS} = -10 \ V, \ I_D = -1 \ mA$ | -0.8 | _ | -2.0 | V |
| Drain course ON registeres | | Deserver | $V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -35 \text{ A}$ | _ | 7.0 | 10 | mΩ |
| Drain-source ON resistance | R _{DS} (ON) | $V_{GS} = -10 \text{ V}, \text{ I}_{D} = -35 \text{ A}$ | _ | 5.6 | 8.0 | | |
| Forward transfer | admittance | Y _{fs} | $V_{DS} = -10 \text{ V}, \text{ I}_{D} = -35 \text{ A}$ | 38 | 75 | _ | S |
| Input capacitance | 9 | C _{iss} | | _ | 9810 | _ | |
| Reverse transfer capacitance | | C _{rss} | $V_{DS}=-10V,V_{GS}=0~V,f=1~MHz$ | | 1130 | | pF |
| Output capacitance | | C _{oss} | | _ | 1500 | _ | |
| Switching time | Rise time | tr | $V_{GS} \xrightarrow{0 \text{ V}}_{-10 \text{ V}} \xrightarrow{I_D}_{0} \xrightarrow{-35 \text{ A}}_{0 \text{ VOUT}}$ | _ | 16 | _ | |
| | Turn-ON time | t _{on} | | | 33 | | - ns |
| | Fall time | t _f | | | 120 | | |
| | Turn-OFF time | t _{off} | | — | 400 | | |
| Total gate charge (gate-source plus gate-drain) | | Qg | $V_{DD} \approx -48$ V, $V_{GS} = -10$ V, $I_D = -70$ A | _ | 246 | _ | |
| Gate-source charge | | Q _{gs} | | | 71 | — | nC |
| Gate-drain ("miller") charge | | Q _{gd} | | — | 87 | — | |

Source-Drain Ratings and Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|------------------|---|-----|------|-----|------|
| Continuous drain reverse current (Note 1) | I _{DR} | — | _ | _ | 70 | А |
| Pulse drain reverse current (Note 1) | I _{DRP} | _ | _ | _ | 280 | А |
| Forward voltage (diode) | V _{DSF} | I _{DR} = -70 A, V _{GS} = 0 V | _ | _ | 1.2 | V |
| Reverse recovery time | t _{rr} | $I_{DR} = -70 \text{ A}, \text{ V}_{GS} = 0 \text{ V},$ | _ | 70 | _ | ns |
| Reverse recovery charge | Q _{rr} | dl _{DR} / dt = 50 A / μs | _ | 53 | _ | nC |

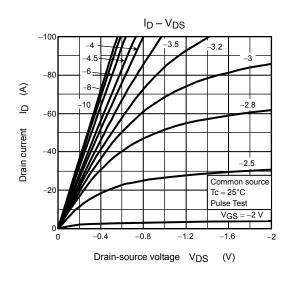
Marking

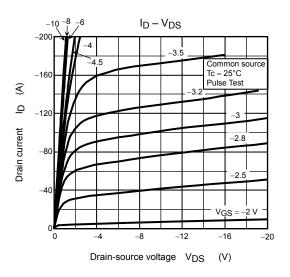


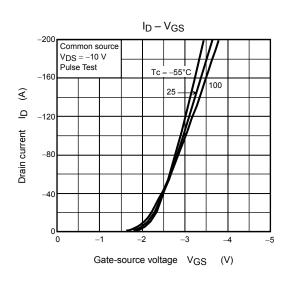
Note 6: A line under a Lot No. identifies the indication of product Labels [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

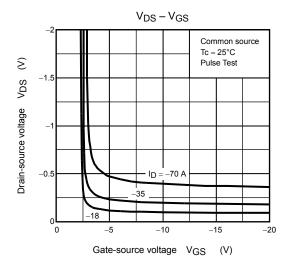
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment

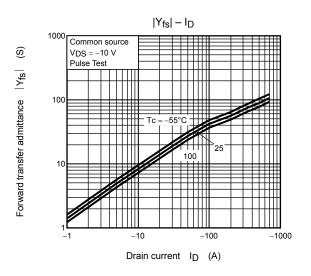
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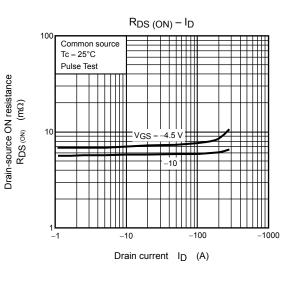


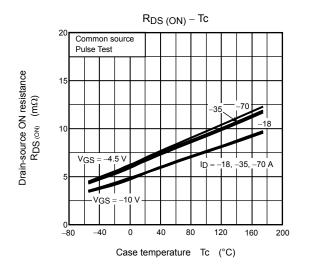


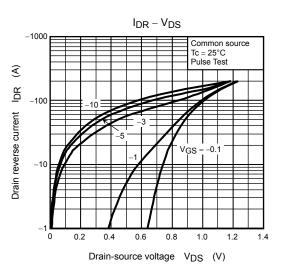


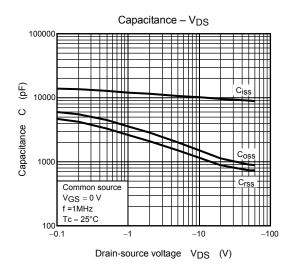


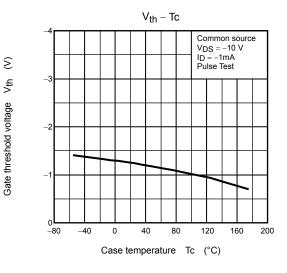


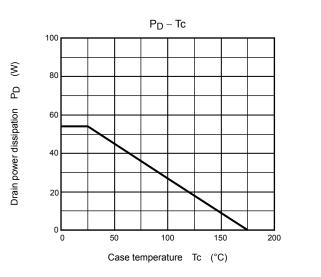


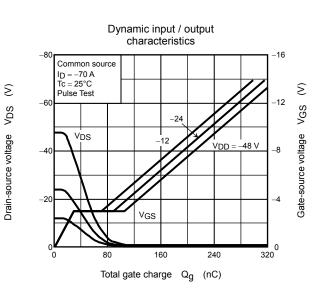


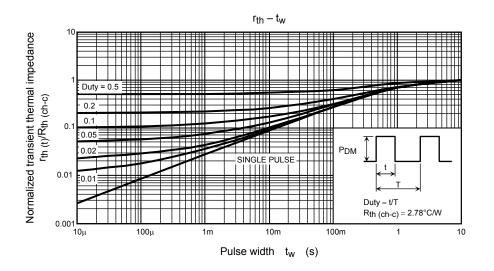




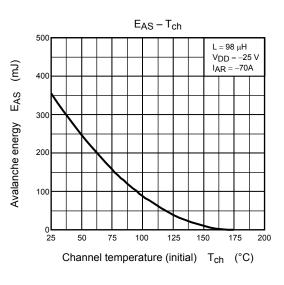


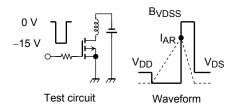






SAFE OPERATING AREA -1000 ### ID max (pulse) * 100 μs 1 ms -100 ŧ E +Drain current I_D DC OPEATION Tc = 25°C -10 ※ Single pulse Tc=25℃ Curves must be derated linearly with increase in temperature. V_{DSS} max -0.1 -0.1 -1 -100 -10 Drain-source voltage V_{DS} (V)





| $R_G = 25 \Omega$ | $E_{AB} = \frac{1}{1} \cdot _{2} \cdot _{2}^{2}$ | BVDSS - VDD | |
|----------------------------|--|-------------|--|
| $V_{DD}=-25~V,~L=98~\mu H$ | LAS 2 | BVDSS-VDD | |

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